

TQN0511T

The TQN0511T is designed with TECHIP process TVS technology to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

Features

- Peak Power Dissipation –40W (8 x 20 us Waveform)
- Stand-off Voltage: 5.0V
- Low capacitance (<15pF) for high-speed interfaces
- No insertion loss to 1GHz
- Protects I/O Port
- Low Clamping Voltage
- Low Leakage
- Meets MSL 1 Requirements
- ROHS compliant
- TECHIP technology

Main applications

- High Speed Line: USB1.0/2.0,VGA
- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV
- Cellular handsets and accessories
- Portable instrumentation
- Peripherals

Protection solution to meet

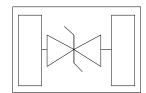
■ IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)

Ordering Information

Device	Package	Qty per Reel	Reel Size
TQN0511T	DFN0603	15,000pcs	7 Inch



DFN0603-2L





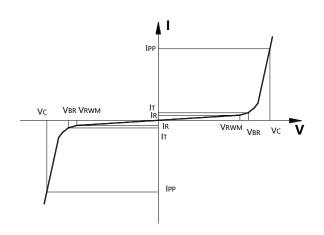
Maximum ratings (Tamb=25°C Unless Otherwise Specified)				
Parameter	Symbol	Value	Unit	
Peak Pulse Power (tp=8/20μs waveform)	Ррр	40	Watts	
ESD Rating per IEC61000-4-2: Contact		30	VV	
Air		30	KV	
Lead Soldering Temperature	TL	260 (10 sec.)	°C	
Operating Temperature Range	τŢ	-55 ~ 150	°C	
Storage Temperature Range	Tstg	-55 ~ 150	°C	
Lead Solder Temperature – Maximum (10 Second Duration)	TL	260	°C	

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

^{1.} Non-repetitive current pulse, per Figure 1.

Electrica	Electrical characteristics (Tamb=25°C Unless Otherwise Specified)					
Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V_{RWM}	Reverse Working Voltage				5.0	V
V_{BR}	Breakdown Voltage	$I_T = 1 \mathrm{mA},$	6.0		12	V
Ir	Reverse Leakage Current	$V_{RWM} = 5V$,		0.001	0.1	uA
Vc Clamping Voltage	Classica Valtara	$I_{PP} = 1A$, $tp = 8/20 \mu s$,		8.7	15	V
	Clamping voltage	$I_{PP} = 4A$, $tp = 8/20 \mu s$,		11.2	16.5	V
C _J	Junction Capacitance	$V_R = 0V$, $f = 1MHz$,		10.2	15	pF
		$V_R = 5V$, $f = 1MHz$,		7.5	15	pF

Symbol	Parameter	
V _{RWM}	Working Peak Reverse Voltage	
V _{BR}	Breakdown Voltage @ IT	
Vc	Clamping Voltage @ IPP	
IT	Test Current	
Irm	Leakage current at VRWM	
IPР	Peak pulse current	
Co	Off-state Capacitance	
C_{J}	Junction Capacitance	



^{*}Other voltages may be available upon request.



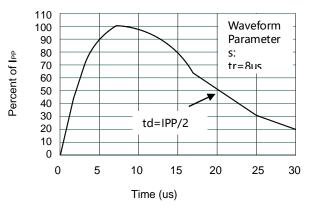
110 100

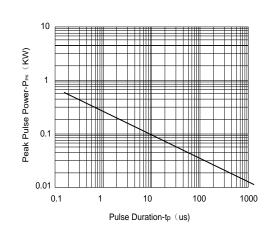
25

50

% of Rated Power or Ipp

Typical electrical characterist applications





Pulse Waveform

Ambient Temperature-T_A (°C)

75

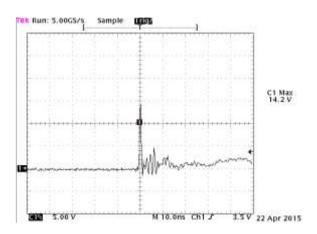
Non-Repetitive Peak Pulse Power vs. Pulse

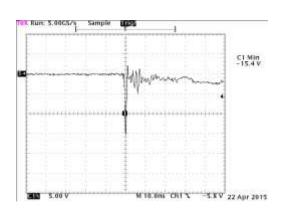
Power Derating Curve

100

125

150





ESD clamp voltage

Positive 8KV IEC61000-4-2 contact

ESD clamp voltage

Negative 8KV IEC61000-4-2 contact



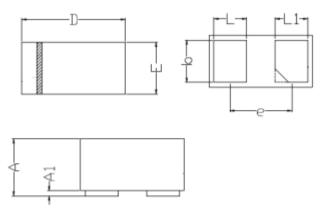
Package Information

DFN0603-2L

Mechanical Data

Case: DFN0603-2L

Case Material: Molded Plastic. UL Flammability



DIM	Millimeters		
DIM	Min	Max	
A	0.230	0.330	
A1	0.000	0.050	
D	0.550	0.650	
E	0.250	0.350	
b	0.215	0.295	
L	0.115	0.225	
L1	0.115	0.225	
e	0.535BSC		

Recommended Pad outline

